Vishay Semiconductors

## Thyristor High Voltage, Phase Control SCR, 30 A



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PRIMARY CHARACTERISTICS					
I <sub>T(AV)</sub>	20 A				
V <sub>DRM</sub> /V <sub>RRM</sub>	1600 V				
V <sub>TM</sub>	1.3 V				
I <sub>GT</sub>	45 mA				
TJ	-40 °C to +125 °C				
Package	TO-247AD 3L				
Circuit configuration	Single SCR				

### FEATURES

- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification



- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

### DESCRIPTION

The VS-30TPS16LHM3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I <sub>T(AV)</sub>	Sinusoidal waveform	20	A			
I <sub>RMS</sub>		30				
V <sub>RRM</sub> /V <sub>DRM</sub>		1600	V			
I <sub>TSM</sub>		300	A			
V <sub>T</sub>	20 A, T <sub>J</sub> = 25 °C	1.3	V			
dV/dt		500	V/µs			
dl/dt		150	A/µs			
TJ		-40 to +125	°C			

VOLTAGE RATINGS							
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA				
VS-30TPS16LHM3	1600	1700	10				

## VS-30TPS16LHM3



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ABSOLUTE MAXIMUM RATING	S				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	$T_C = 95 \ ^{\circ}C$ , 180° conduction	half sine wave	20	
Maximum RMS on-state current	I <sub>RMS</sub>			30	А
Maximum peak, one-cycle,		10 ms sine pulse, rated V <sub>RRM</sub> applied		250	A
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage	reapplied	300	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated $V_{\text{RRM}}$	applied	310	A <sup>2</sup> s
Maximum intro rusing	1-1	10 ms sine pulse, no voltage reapplied		442	A-2
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 to 10 ms, no voltage re	4420	A²√s	
Maximum on-state voltage drop	V <sub>TM</sub>	20 A, T <sub>J</sub> = 25 °C		1.3	V
On-state slope resistance	r <sub>t</sub>	T,ı = 125 °C		12	mΩ
Threshold voltage	V <sub>T(TO)</sub>	1j = 125 C		1.0	V
Maximum reverse and direct leakage current	1 /1	T <sub>J</sub> = 25 °C	$V = rotod V$ $\Lambda/$	0.5	
Maximum reverse and direct leakage current	I <sub>RM</sub> /I <sub>DM</sub>	$V_{\rm R}$ = rated $V_{\rm RRM}/V_{\rm DRM}$		10	mA
Maximum holding current	Ι <sub>Η</sub>	Anode supply = 6 V, resistive load, initial $I_T$ = 1 A, $T_J$ = 25 °C		150	ma
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$		200	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80	0 % V <sub>DRM</sub> , R <sub>g</sub> - k = open	500	V/µs
Maximum rate of rise of turned-on current	dl/dt			150	A/µs

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P <sub>GM</sub>		8.0	W	
Maximum average gate power	P <sub>G(AV)</sub>		2.0	vv	
Maximum peak positive gate current	+ I <sub>GM</sub>		1.5	А	
Maximum peak negative gate voltage	- V <sub>GM</sub>		10	V	
	I <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J$ = - 10 °C	60	mA	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J$ = 25 °C	45		
		Anode supply = 6 V, resistive load, $T_J$ = 125 °C	20		
		Anode supply = 6 V, resistive load, $T_J$ = - 10 °C	2.5		
Maximum required DC gate voltage to trigger	V <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J$ = 25 °C	2.0	v	
		Anode supply = 6 V, resistive load, $T_J$ = 125 °C	1.0	v	
Maximum DC gate voltage not to trigger	V <sub>GD</sub>	$T = 125 $ °C $V_{\rm e}$ = rotad value	0.25		
Maximum DC gate current not to trigger	I <sub>GD</sub>	$T_J = 125 \text{ °C}, V_{DRM} = \text{rated value}$	2.0	mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t <sub>gt</sub>	$T_J = 25 \text{ °C}$	0.9	
Typical reverse recovery time	t <sub>rr</sub>	T., = 125 °C	4	μs
Typical turn-off time	tq	1] = 125 0	110	

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## VS-30TPS16LHM3



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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to 125	°C		
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.8			
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W		
Maximum thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2			
Approvimate weight				6	g		
Approximate weight				0.21	oz.		
Mounting torquo	minimum			6 (5)	kgf ⋅ cm		
Mounting torque -	maximum			12 (10)	(lbf · in)		
Marking device			Case style TO-247AD 3L	30TP	S16H		

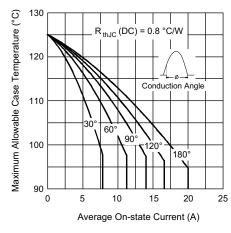


Fig. 1 - Current Rating Characteristics

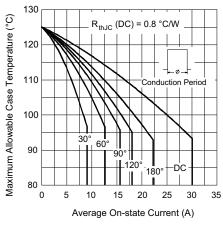


Fig. 2 - Current Rating Characteristics

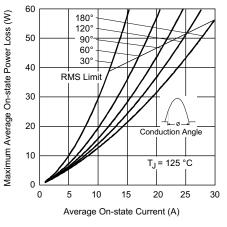


Fig. 3 - On-State Power Loss Characteristics

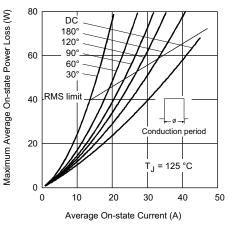
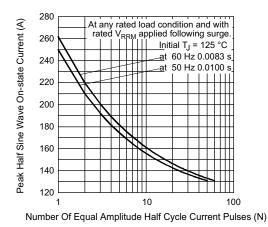


Fig. 4 - On-State Power Loss Characteristics

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Fig. 5 - Maximum Non-Repetitive Surge Current

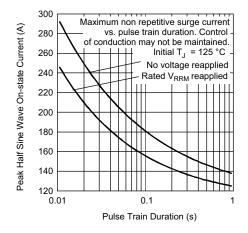


Fig. 6 - Maximum Non-Repetitive Surge Current

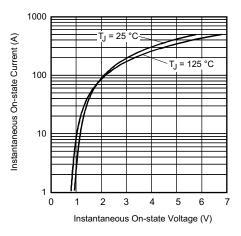


Fig. 7 - On-State Voltage Drop Characteristics

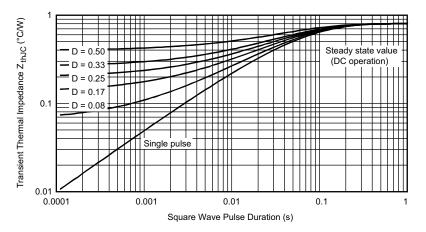
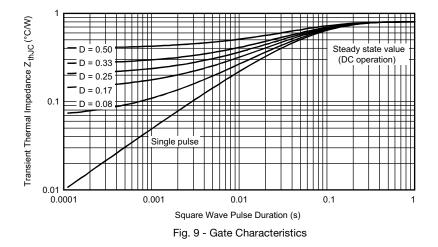


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

# VS-30TPS16LHM3

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### **ORDERING INFORMATION TABLE**

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ISHAY

Device code	vs-	30	т	Р	S	16	L	н	МЗ
	1	2	(3)	4	(5)	6	(7)	(8)	(9)
l	1 -	Vish	ay Sem	niconduc	ctors pro	oduct			
	2 -	Cur	rent rati	ng (30 =	: 30 A)				
	3 -	Circ	uit conf	iguratio	n:				
		Τ =	thyristo	r					
	4 -	Pac	kage:						
		P =	TO-247						
	5 -	Тур	e of silic	con:					
		S =	standar	d recove	ery rectif	fier			
	6 -	Volt	age rati	ng (16 =	1600 V	)			
	7 -	Pac	kage L :	= long le	ad				
	8 -		-	- 101 qua					
	9 -			•					
				tal digit:		omolion	t and t	rminet	ono loo
		11/13 =	- naioge	en-free, l	RoHS-co	omplian	i, and te	erminati	uns iea

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-30TPS16LHM3	25	500	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95626				
Part marking information	www.vishay.com/doc?95007				

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TO-247AD 3L

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	254	0.0	)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- <sup>(3)</sup> Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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